



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re the Application of:

Geum-Jong BAE, et al

Art Unit: 2814

Serial No. 10/659,384

Examiner: H.V. Pham

Filed: September 11, 2003

Confirmation No. 3795

For: MOS TRANSISTOR HAVING A T-SHAPED GATE ELECTRODE AND METHOD FOR FABRICATING THE SAME

Attorney Docket No. 239/169 DIV

AMENDMENT UNDER 37 C.F.R. § 1.111

Mail Stop Amendment
Commissioner for Patents
United States Patent and Trademark Office
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office action dated June 29, 2005, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

Amendments to the Claims are reflected in a listing of claims, which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.